LM2412A

LM2412A Monolithic Triple 2.8 ns CRT Driver



Literature Number: SNOS947A

LM2412A

Monolithic Triple 2.8 ns CRT Driver

General Description

The LM2412A is an integrated high voltage CRT driver circuit designed for use in high resolution color monitor applications. The IC contains three high input impedance, wide band amplifiers which directly drive the RGB cathodes of a CRT. Each channel has its gain internally set to –14 and can drive CRT capacitive loads as well as resistive loads presented by other applications, limited only by the package's power dissipation.

The IC is packaged in an industry standard 11 lead TO-220 molded plastic power package. See thermal considerations section for heat sinking requirements.

Features

■ Rise/fall times typically 2.8 ns with 8 pF load at 40 V_{PP}

- Faster Maximum Rise/Fall time than LM2412, 3.2nsec vs 3.5nsec.
- Well matched with LM2202 video preamps
- Output swing capability: 50 V_{PP} for V_{CC} = 80V
- 1V to 5V input range
- Stable with 0-20 pF capacitive loads and inductive peaking networks
- Convenient TO-220 staggered lead package style
- Standard LM240X family pinout which is designed for easy PCB layout

Applications

- CRT driver for color monitors with display resolutions up to 1600 x 1200 with 85 Hz refresh rate
- Pixel clock frequency up to 200 MHz

Schematic and Connection Diagrams

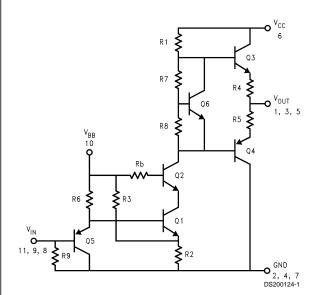
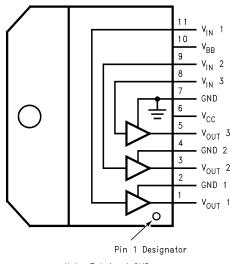


FIGURE 1. Simplified Schematic Diagram (One Channel)



Note: Tab is at GND

DS200124-2

Top View Order Number LM2412ATA See NS package Number

Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage, V_{CC} +90V Bias Voltage, V_{BB} +16V Input Voltage, V_{IN} 0V to 6V Storage Temperature Range, T_{STG} -65°C to +150°C Lead Temperature (Soldering, <10 sec.) 300°C

ESD Tolerance
Human Body Model 2 kV
Machine Model 250V

Operating Ranges (Note 3)

 $\begin{array}{lll} V_{CC} & +60 \text{V to } +85 \text{V} \\ V_{BB} & +8 \text{V to } +15 \text{V} \\ V_{IN} & +1 \text{V to } +5 \text{V} \\ V_{OUT} \text{ (V_{CC} = 80$V, V_{BB} = 12V)} & +15 \text{V to } +75 \text{V} \\ \text{Case Temperature} & -20 ^{\circ} \text{C to } +100 ^{\circ} \text{C} \\ \end{array}$

Do not operate the part without a heat sink.

Electrical Characteristics

(See Figure 2 for Test Circuit)

Unless otherwise noted: V_{CC} = +80V, V_{BB} = +12V, V_{IN} = +3.3 V_{DC} , C_L = 8 pF, T_C = 60°C, no AC input.

Symbol	Parameter	Conditions	LM2412A			Units
			Min	Тур	Max	Units
I _{CC}	Supply Current	Per Channel, No Output Load	16	21	26	mA
I _{BB}	Bias Current	All Three Channels	27	42	57	mA
V _{OUT}	DC Output Voltage	V _{IN} = 1.9V	62	65	68	V _{DC}
A _V	DC Voltage Gain		-12	-14	-16	
ΔA_{V}	Gain Matching	(Note 4)		1.0		dB
LE	Linearity Error	(Notes 4, 5)		3.5		%
t _r	Rise Time (Notes 6, 7)	10% to 90%, 40 V _{PP} Output (1 MHz)		2.8	3.2	ns
t _f	Fall Time (Notes 6, 7)	10% to 90%, 40 V _{PP} Output (1 MHz)		2.8	3.2	ns
OS	Overshoot	40 V _{PP} Output (1 MHz)		5		%

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" specifies conditions of device operation.

Note 2: All voltages are measured with respect to GND, unless otherwise specified.

Note 3: Operating ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may change when the device is not operated under the listed test conditions.

Note 4: Calculated value from voltage gain test on each channel.

Note 5: Linearity error is the variation in DC gain from $V_{IN} = 1.6V$ to $V_{IN} = 5.0V$.

Note 6: Input from signal generator: t_r , $t_f < 1$ ns.

Note 7: 100% tested in production. These limits are not used to calculate outgoing quality levels.

AC Test Circuit

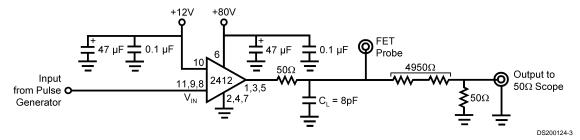


FIGURE 2. Test Circuit (One Channel)

Figure 2 shows a typical test circuit for evaluation of the LM2412A. This circuit is designed to allow testing of the LM2412A in a 50Ω environment without the use of an expensive FET probe. The combined resitors of 4950Ω at the output form a 200:1 voltage divider when connected to a 50Ω load. The test board supplied by NSC also offers the option to test theLM2412A with a FET probe. C_L is the total

capacitance at the LM2412A output, including the board capacitance.

Typical Performance Characteristics

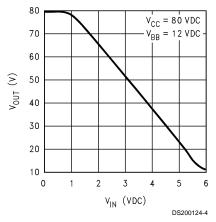


FIGURE 3. V_{IN} vs V_{OUT}

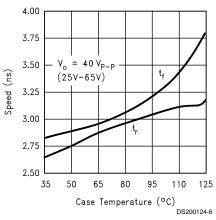


FIGURE 4. Speed vs Temp.

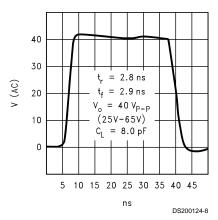


FIGURE 5. Rise/Fall Time

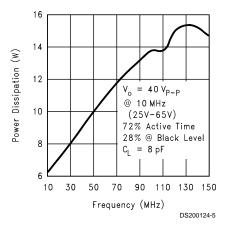


FIGURE 6. Power Dissipation vs Frequency

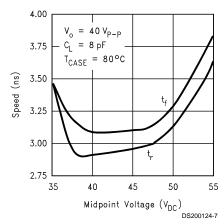


FIGURE 7. Speed vs Offset

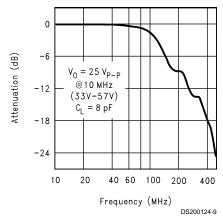


FIGURE 8. Bandwidth

Theory of Operation

The LM2412A is a high voltage monolithic three channel CRT driver suitable for very high resolution display applications, up to 1600 x 1200 at 85 Hz refresh rate. The LM2412A operates using 80V and 12V power supplies. The part is housed in the industry standard 11-lead TO-220 molded plastic power package.

The simplified circuit diagram of one channel of the LM2412A is shown in Figure 1. A PNP emitter follower, Q5, provides input buffering. This minimizes the current loading of the video pre-amp. R9 is used to turn on Q5 when there is no input. With Q5 turned on, Q1 will be almost completely off, minimizing the current flow through Q1 and Q2. This will drive the output stage near the V_{CC} rail, minimizing the power dissipation with no inputs. R6 is a pull-up resistor for Q5 and also limits the current flow through Q5. R3 and R2 are used to set the current flow through Q1 and Q2. The ratio of R1 to R2 is used to set the gain of the LM2412A. R1, R2 and R3 are all related when calculating the output voltage of the CRT driver. R_b limits the current through the base of Q2. Q1 and Q2 are in a cascode configuration. Q1 is a low voltage and very fast transistor. Q2 is a higher voltage transistor. The cascode configuration gives the equivalent of a very fast and high voltage transistor. The two output transistors, Q3 and Q4, form a class B amplifier output stage. R4 and R5 are used to limit the current through the output stage and set the output impedance of the LM2412A. Q6, along with R7 and R8 set the bias current through Q3 and Q4 when there is no change in the signal level. This bias current minimizes the crossover distortion of the output stage. With this bias current the output stage now becomes a class AB amplifier with a crossover distortion much lower than a class B amplifier.

Figure 2 shows a typical test circuit for evaluation of the LM2412A. Due to the very wide bandwidth of the LM2412A, it is highly recommended that the stand alone board suplied by NSC be used for the evaluation of the CRT driver's performance. The 50Ω resistor is used to duplicate the required series resistor in the actual application. This resistor would be part of the arc-over protection circuit. The input signal from the generator is AC coupled to the input of the CRT driver.

Application Hints

INTRODUCTION

National Semiconductor (NSC) is committed to providing application information that assists our customers in obtaining the best performance possible from our products. The following information is provided in order to support this commitment. The reader should be aware that the optimization of performance was done using a specific printed circuit board designed at NSC. Variations in performance can be realized due to physical changes in the printed circuit board and the application. Therefore, the designer should know that component value changes may be required in order to optimize performance in a given application. The values shown in this document can be used as a starting point for evaluation purposes. When working with high bandwidth circuits, good layout practices are also critical to achieving maximum performance.

POWER SUPPLY BYPASS

Since the LM2412A is a very high bandwidth amplifier, proper power supply bypassing is critical for optimum performance. Improper power supply bypassing can result in large overshoot, ringing and oscillation. A 0.1 μF capacitor should be connected from the supply pin, $V_{\rm CC}$, to ground, as close to the supply and ground pins as is practical. Additionally, a 10 μF to 100 μF electrolytic capacitor should be connected from the supply pin to ground. The electrolytic capacitor should also be placed reasonably close to the LM2412A's supply and ground pins. A 0.1 μF capacitor should be connected from the bias pin, $V_{\rm BB}$, to ground, as close as is practical to the part.

ARC PROTECTION

During normal CRT operation, internal arcing may occasionally occur. Spark gaps, in the range of 200V, connected from the CRT cathodes to CRT ground will limit the maximum voltage, but to a value that is much higher than allowable on the LM2412A. This fast, high voltage, high energy pulse can damage the LM2412A output stage. The application circuit shown in Figure 9 is designed to help clamp the voltage at the output of the LM2412A to a safe level. The clamp diodes should have a fast transient response, high peak current rating, low series impedance and low shunt capacitance. FDH400 or equivalent diodes are recommended. D1 and D2 should have short, low impedance connections to V_{CC} and ground respectively. The cathode of D1 should be located very close to a separately decoupled bypass capacitor. The ground connection of the diode and the decoupling capacitor should be very close to the LM2412A ground. This will significantly reduce the high frequency voltage transients that the LM2412A would be subjected to during an arc-over condition. Resistor R2 limits the arc-over current that is seen by the diodes while R1 limits the current into the LM2412A as well as the voltage stress at the outputs of the device. R2 should be a ½W solid carbon type resistor. R1 can be a ¼W metal or carbon film type resistor. Inductor L1 is critical to reduce the initial high frequency voltage levels that the LM2412A would be subjected to during an arc-over. Having large value resistors for R1 and R2 would be desirable, but this has the effect of increasing rise and fall times. The inductor will not only help protect the device but it will also help optimize rise and fall times as well as minimize EMI. For proper arc protection, it is important to not omit any of the arc protection components shown in Figure 9. The values of L1 and R1 may need to be adjusted for a particular application. The recommended minimum value for R1 is 75Ω , with L1 = .049 uH.

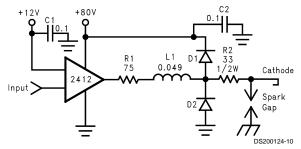


FIGURE 9. One Channel of the LM2412A with the Recommended Arc Protection Circuit.

OPTIMIZING TRANSIENT RESPONSE

Referring to *Figure 9*, there are three components (R1, R2 and L1) that can be adjusted to optimize the transient response of the application circuit. Increasing the values of R1 and R2 will slow the circuit down while decreasing overshoot. Increasing the value of L1 will speed up the circuit as well as increase overshoot. It is very important to use inductors with very high self-resonant frequencies, preferably above 300 MHz. Air core inductors from J.W. Miller Magnetics (part #75F518MPC) were used for optimizing the performance of the device in the NSC application board. The values shown in *Figure 9* can be used as a good starting point for the evaluation of the LM2412A.

Effect of Load Capacitance

The output rise and fall times as well as overshoot will vary as the load capacitance varies. The values of the output circuit (R1, R2 and L1 in *Figure 9*) should be chosen based on the nominal load capacitance. Once this is done the performance of the design can be checked by varying the load based on what the expected variation will be during production.

Effect of Offset

Figure 7 shows the variation in rise and fall times when the output offset of the device is varied from 35 to 55 $V_{\rm DC}$. The rise and fall times show about the same overall variation. The slightly slower fall time is fastest near the center point of 45V, making this the optimum operating point. At the low and high output offset range, the characteristic of rise/fall time is slower due to the saturation of Q3 and Q4. The recovery time of the output transistors takes longer coming out of saturation thus slows down the rise and fall times.

THERMAL CONSIDERATIONS

Figure 4 shows the performance of the LM2412A in the test circuit shown in Figure 2 as a function of case temperature. Figure 4 shows that both the rise and fall times of the LM2412A become slightly longer as the case temperature increases from 40°C to 125°C. In addition to exceeding the safe operating temperature, the rise and fall times will typically exceed 3 nsec. Please note that the LM2412A is never to be operated over a case temperature of 100°C. In addition to exceeding the safe operating temperature, the rise and fall times will typically exceed 3 nsec.

Figure 6 shows the total power dissipation of the LM2412A vs. Frequency when all three channels of the device are driving an 8 pF load. Typically the active time is about 72% of the total time for one frame. Worst case power dissipation is when a one on, one off pixel is displayed over the active time of the video input. This is the condition used to measure the total power disspation of the LM2412A at different input frequencies. Figure 6 gives all the information a monitor designer normally needs for worst case power dissipation. However, if the designer wants to calculate the power dissipation for an active time different from 72%, this can be done using the information in Figure 14. The recommended input black level voltage is 1.9V. From Figure 14, if a 1.9V input is used for the black level, then power dissipation during the inactive video time is 2.7W. This includes both the 80V and 12V supplies.

If the monitor designer chooses to calculate the power dissipation for the LM2412A using an active video time different from 72%, then he needs to use the following steps when using a 1.9V input black level:

- Multiply the black level power dissipation, 2.7W, by 0.28, the result is 0.8W.
- Choose the maximum frequency to be used. A typical application would use 100 MHz, or a 200 MHz pixel clock. The power dissipation is 13.8W.
- 3. Subtract the 0.8W from the power dissipation from Figure 6. For 100 MHz this would be 13.8 0.8 = 13.0W.
- Divide the result from step 3 by 0.72. For 100 MHz, the result is 18.1W.
- Multiply the result in 4 by the new active time percentage.
- 6. Multiply 2.7W by the new inactive time.
- Add together the results of steps 5 and 6. This is the expected power dissipation for the LM2412A in the designer's application.

The LM2412A case temperature must be maintained below 100°C. If the maximum expected ambient temperature is 70°C and the maximum power dissipation is 13.8W (from Figure 6. 100MHz) then a maximum heat sink thermal resistance can be calculated:

$$TH = \frac{100 \text{°C} - 70 \text{°C}}{13.8 \text{W}} = 2.2 \text{°C/W}$$

TYPICAL APPLICATION

A typical application of the LM2412A is shown in *Figure 10*. Used in conjunction with three LM2202s, a complete video channel from monitor input to CRT cathode can be achieved. Performance is excellent for resolutions up to 1600 x 1200 and pixel clock frequencies at 200 MHz. *Figure 10* is the schematic for the NSC demonstration board that can be used to evaluate the LM2202/LM2412A combination in a monitor.

PC Board Layout Considerations

For optimum performance, an adequate ground plane, isolation between channels, good supply bypassing and minimizing unwanted feedback are necessary. Also, the length of the signal traces from the preamplifier to the LM2412A and from the LM2412A to the CRT cathode should be as short as possible. The red video trace from the buffer transistor to the LM2412A input is about the absolute maximum length one should consider on a PCB layout. If possible the traces should actually be shorter than the red video trace. The following references are recommended for video board designers:

Ott, Henry W., "Noise Reduction Techniques in Electronic Systems", John Wiley & Sons, New York, 1976.

"Guide to CRT Video Design", National Semiconductor Application Note 861.

"Video Amplifier Design for Computer Monitors", National Semiconductor Application Note 1013.

Pease, Robert A., "Troubleshooting Analog Circuits", Butterworth-Heinemann, 1991.

Because of its high small signal bandwidth, the part may oscillate in a monitor if feedback occurs around the video channel through the chassis wiring. To prevent this, leads to the video amplifier input circuit should be shielded, and input circuit wiring should be spaced as far as possible from output circuit wiring.

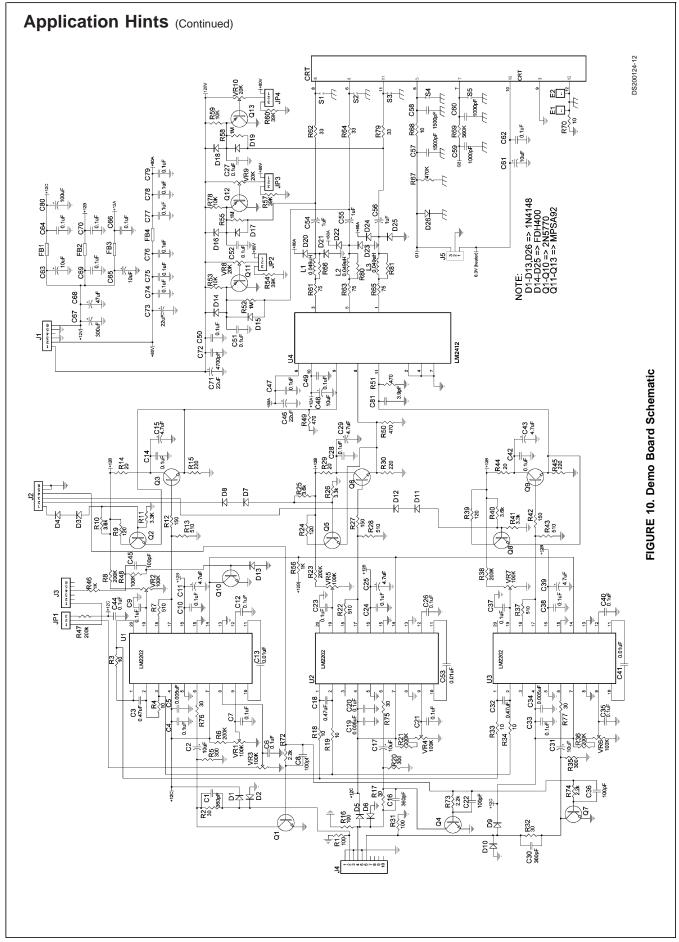
NSC Demonstration Board

Figures 11, 12 show routing and component placement on the NSC LM2202/2412 demonstration board. The schematic of the board is shown in Figure 10. This board provides a good example of a layout that can be used as a guide for future layouts. Note the location of the following components:

- C47 V_{CC} bypass capacitor, located very close to pin 6 and ground pins. (Figure 12)
- C49 V_{BB} bypass capacitor, located close to pin 10 and ground. (Figure 12)
- C46 and C77 V_{CC} bypass capacitors, near LM2412A and V_{CC} clamp diodes. Very important for arc protection. (Figure 11)

The routing of the LM2412A outputs to the CRT is very critical to achieving optimum performance. *Figure 13* shows the routing and component placement from pin 1 to the blue

cathode. Note that the components are placed so that they almost line up from the output pin of the LM2412A to the blue cathode pin of the CRT connector. This is done to minimize the length of the video path between these two components. The direct video path is shown in by a dark gray line through the components and the PCB traces. Note also that D24, D25, R58 and D19 are placed to keep the size of the video nodes to a minimum (R58 is located under D19). This minimizes parasitic capacitance in the video path and also enhances the effectiveness of the protection diodes. The traces in the video nodes to these components are shown by the white line. The anode of protection diode D25 is connected directly to the ground plane giving a short and direct path to the LM2412A ground pins. The cathode of D24 is connected to V_{CC} very close to decoupling capacitor C78 (Figure 13) which is connected to the same section of the ground plane as D25. The diode placement and routing is very important for minimizing the voltage stress on the LM2412A during an arc-over event. Lastly, notice that S3 is placed very close to the blue cathode and is tied directly to CRT ground.



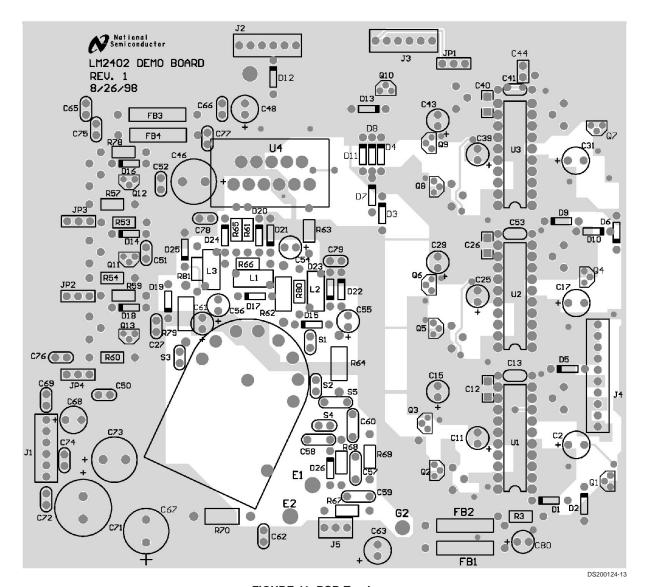


FIGURE 11. PCB Top Layer

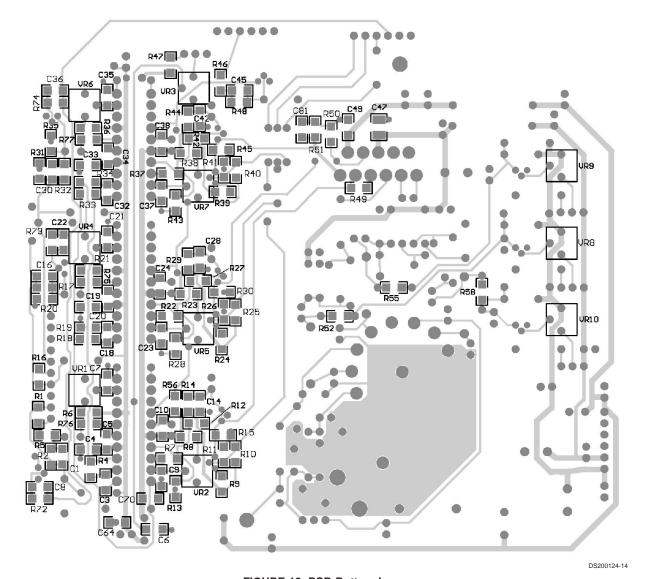


FIGURE 12. PCB Bottom Layer

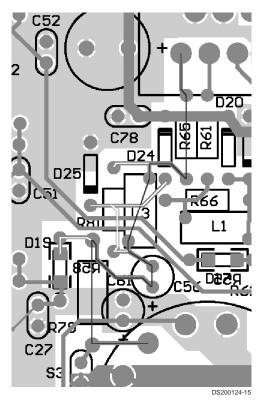


FIGURE 13. PCB CRT Driver, Blue Channel Output

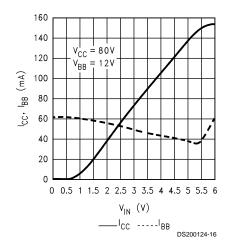
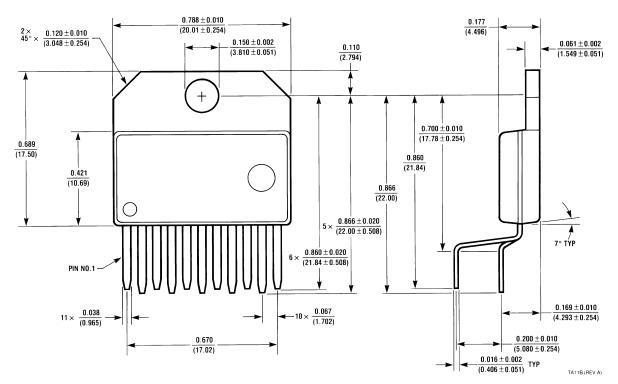


FIGURE 14. $I_{\rm CC}$ and $I_{\rm BB}$ vs $V_{\rm IN}$

Physical Dimensions inches (millimeters) unless otherwise noted



11 Lead Molded TO-220 NS Package Number TA11B Order Number LM2412ATA

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation

Americas
Tel: 1-800-272-9959
Fax: 1-800-737-7018
Email: support@nsc.com

www.national.com

National Semiconductor Europe

Fax: +49 (0) 180-530 85 86

Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 69 9508 6208
English Tel: +44 (0) 870 24 0 2171
Français Tel: +33 (0) 1 41 91 8790

National Semiconductor Asia Pacific Customer Response Group Tel: 65-2544466 Fax: 65-2504466

Fax: 65-2504466 Email: ap.support@nsc.com National Semiconductor Japan Ltd. Tel: 81-3-5639-7560

Fax: 81-3-5639-7507

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products Applications

Audio www.ti.com/audio Communications and Telecom www.ti.com/communications **Amplifiers** amplifier.ti.com Computers and Peripherals www.ti.com/computers dataconverter.ti.com Consumer Electronics www.ti.com/consumer-apps **Data Converters DLP® Products** www.dlp.com **Energy and Lighting** www.ti.com/energy DSP dsp.ti.com Industrial www.ti.com/industrial Clocks and Timers www.ti.com/clocks Medical www.ti.com/medical

Interface interface.ti.com Security www.ti.com/security

Logic Space, Avionics and Defense www.ti.com/space-avionics-defense

Power Mgmt power.ti.com Transportation and Automotive www.ti.com/automotive
Microcontrollers Microcontroller.ti.com Video and Imaging www.ti.com/video

RFID <u>www.ti-rfid.com</u>
OMAP Mobile Processors www.ti.com/omap

Wireless Connectivity www.ti.com/wirelessconnectivity

TI E2E Community Home Page <u>e2e.ti.com</u>